

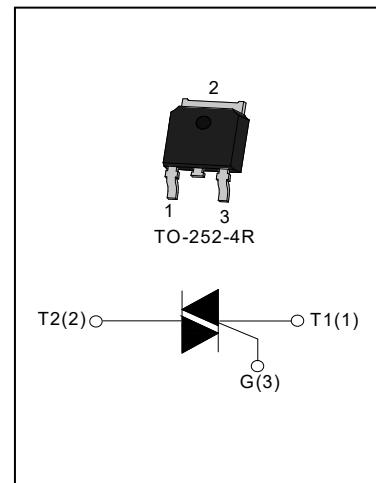


JST134 Series 4A TRIACS

Rev.16.0

DESCRIPTION:

JST134 series triacs with low holding and latching current are especially recommended for use on middle and small resistance type power load. Package TO-252-4R is RoHS compliant. (201/65/EU)



MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	4	A
V_{DRM} / V_{RRM}	600/800	V

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40 - 150	°C
Operating junction temperature range	T_j	-40 - 125	°C
Repetitive peak off-state voltage($T_j=25^\circ\text{C}$)	V_{DRM}	600/800	V
Repetitive peak reverse voltage($T_j=25^\circ\text{C}$)	V_{RRM}	600/800	V
Non repetitive surge peak Off-state voltage	V_{DSM}	$V_{DRM} + 100$	V
Non repetitive peak reverse voltage	V_{RSM}	$V_{RRM} + 100$	V
RMS on-state current ($T_c=110^\circ\text{C}$)	$I_{T(RMS)}$	4	A
Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$)	I_{TSM}	30	A
I^2t value for fusing ($t_p = 10\text{ms}$)	I^2t	4.5	A^2s
Critical rate of rise of on-state current ($I_G = 2 \times I_{GT}$)	I - II - III IV	50 10	$\text{A}/\mu\text{s}$
Peak gate current	I_{GM}	2	A
Average gate power dissipation	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	5	W
Peak pulse voltage ($T_j=25^\circ\text{C}$; non-repetitive,off-state;FIG.10)	V_{PP}	2.5	kV

ELECTRICAL CHARACTERISTICS ($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant		Value			Unit
				T	D	E	
I_{GT}	$V_D=12V$ $R_L=33\Omega$	I - II - III	MAX	5	5	10	mA
		IV		5	10	25	
V_{GT}		ALL	MAX	1.3			V
V_{GD}	$V_D=V_{DRM}$ $T_j=125^\circ\text{C}$ $R_L=3.3K\Omega$	ALL	MIN	0.2			V
I_L	$I_G=1.2I_{GT}$	I - III - IV	MAX	8	10	20	mA
		II		12	15	35	
I_H	$I_T=100\text{mA}$		MAX	5	10	20	mA
dV/dt	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ\text{C}$		MIN	20	50	100	V/ μ s
(dV/dt)c	(dI/dt)c=1.1A/ms $T_j=125^\circ\text{C}$		MIN	0.5	1	5	V/ μ s

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V_{TM}	$I_{TM}=5\text{A}$ $tp=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.7	V
V_{TO}	Threshold voltage	$T_j=125^\circ\text{C}$	1	V
R_d	Dynamic resistance	$T_j=125^\circ\text{C}$	105	m Ω
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25^\circ\text{C}$	5	μA
I_{RRM}		$T_j=125^\circ\text{C}$	0.5	mA

THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-252-4R	2.58	°C/W
$R_{th(j-a)}$	junction to ambient		70	

ORDERING INFORMATION

J	ST	134	K	-600	D	-/
JieJie Microelectronics Co.,Ltd						
	TRIACs					
		IT(RMS):4A				
			K:TO-252-4R			
						Blank: Tube TR: Tape & Reel
						T:IGT1-3≤5mA IGT4≤5mA D:IGT1-3≤5mA IGT4≤10mA E:IGT1-3≤10mA IGT4≤25mA
						600:V _{DRM} V _{RRM} ≥600V 800:V _{DRM} V _{RRM} ≥800V

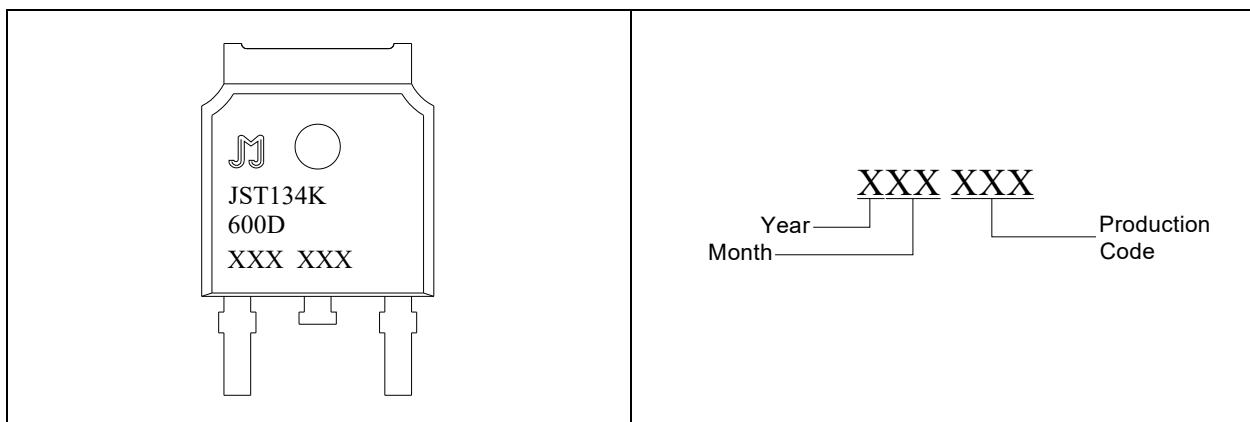
MARKING

FIG.1: Maximum power dissipation versus RMS on-state current

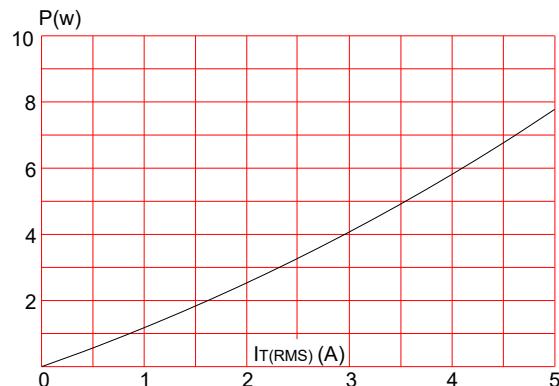


FIG.3: RMS on-state current versus case temperature

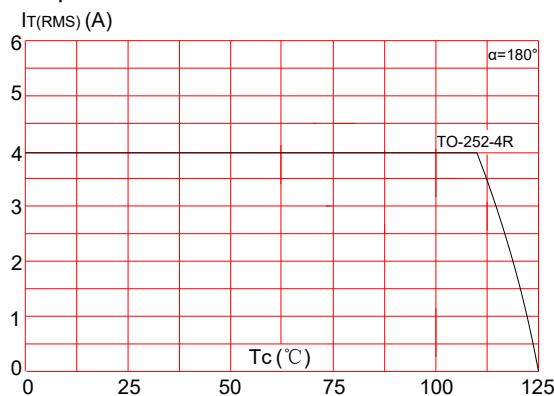


FIG.5: On-state characteristics (maximum values)

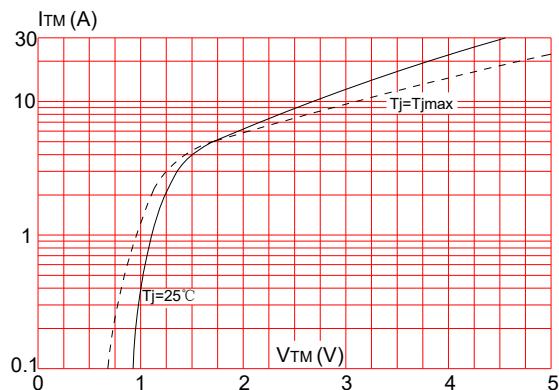


FIG.2: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35μm) (full cycle)

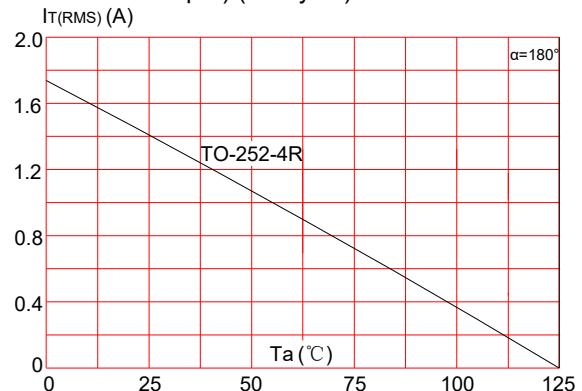


FIG.4: Surge peak on-state current versus number of cycles

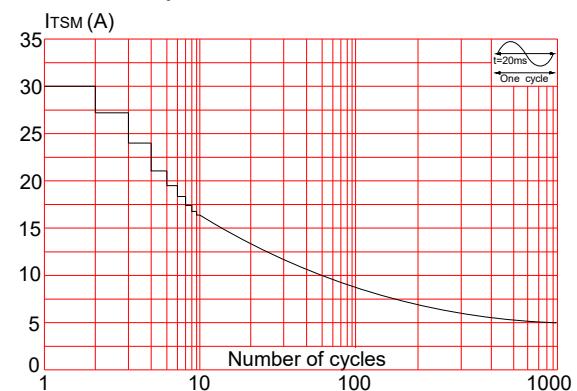


FIG.6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $tp < 20\text{ms}$ and corresponding value of I^2t ($I - II - III: dI/dt < 50\text{A}/\mu\text{s}$; IV: $dI/dt < 10\text{A}/\mu\text{s}$)

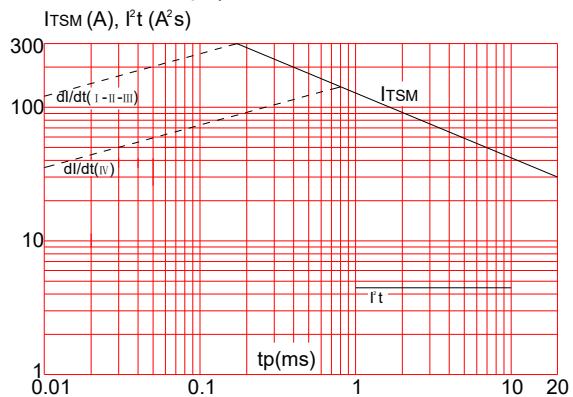


FIG.7: Relative variations of gate trigger current versus junction temperature

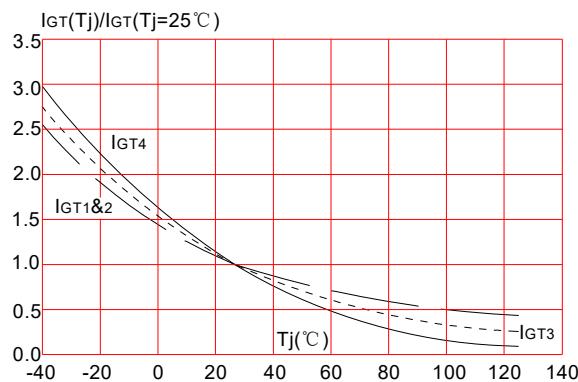


FIG.8: Relative variations of holding current versus junction temperature

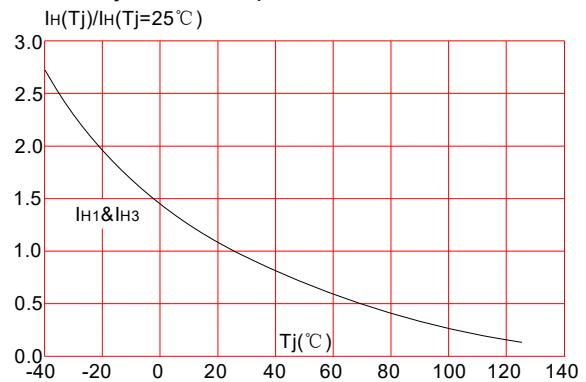


FIG.9: Relative variations of latching current versus junction temperature

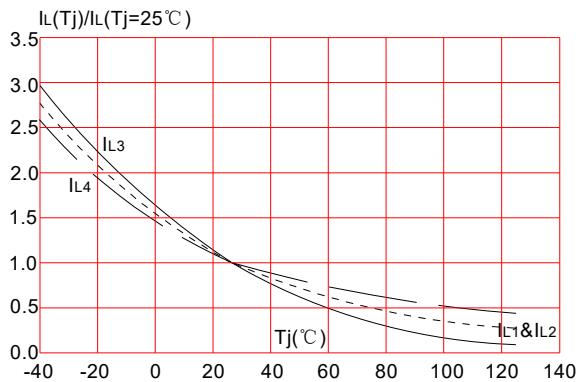
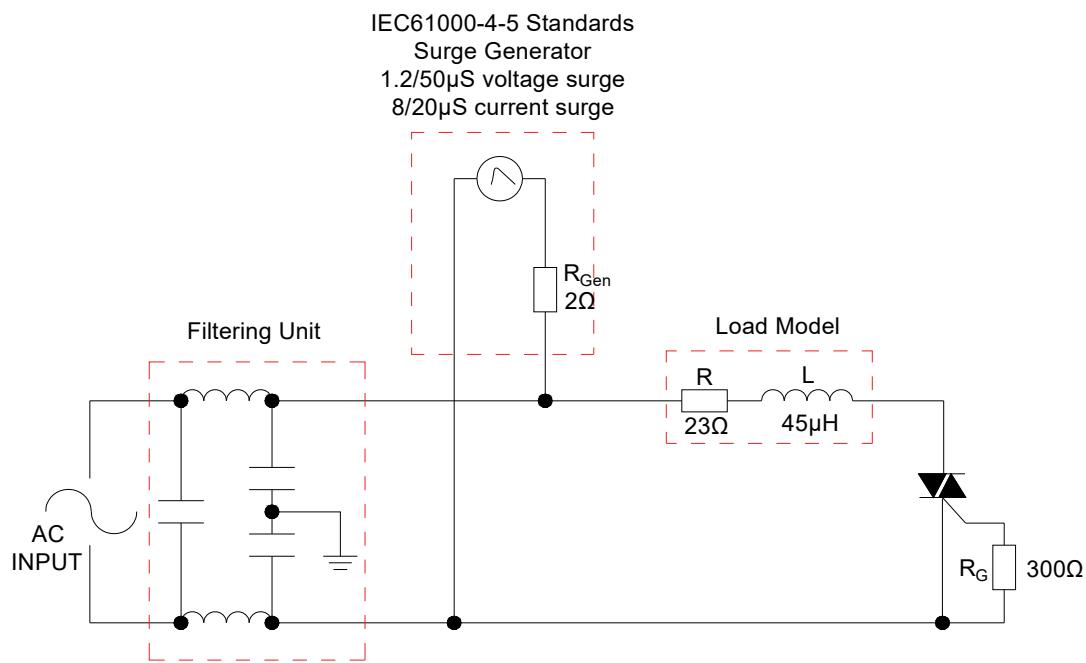
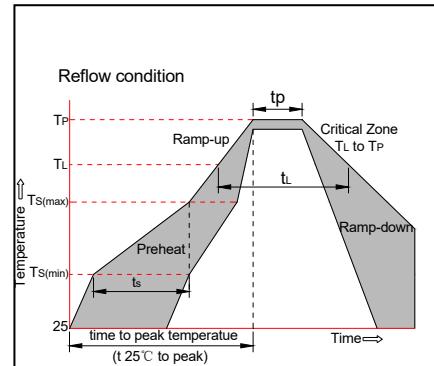


FIG.10: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ($T_{s(\min)}$)	+150 °C
	-Temperature Max($T_{s(\max)}$)	+200 °C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L) to peak)		3 °C/sec. Max
$T_{s(\max)}$ to T_L - Ramp-up Rate		3 °C/sec. Max
Reflow	-Temperature(T_L) (Liquidus)	+217 °C
	-Temperature(t_p)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5) °C
Time within 5 °C of actual Peak Temp (t_p)		20-40secs.
Ramp-down Rate		6 °C/sec. Max
Time 25 °C to Peak Temp (T_p)		8 min. Max
Do not exceed		+260 °C



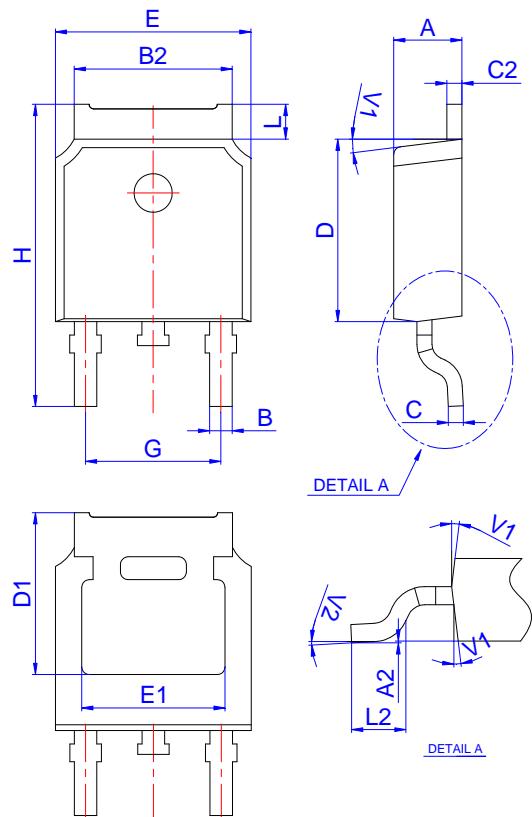
ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		I -II-III	IV			
JST134K-600/800T	600/800	5	5	TO-252-4R	80 2,500	Tube Tape & Reel
JST134K-600/800D		5	10			
JST134K-600/800E		10	25			

Document Revision History

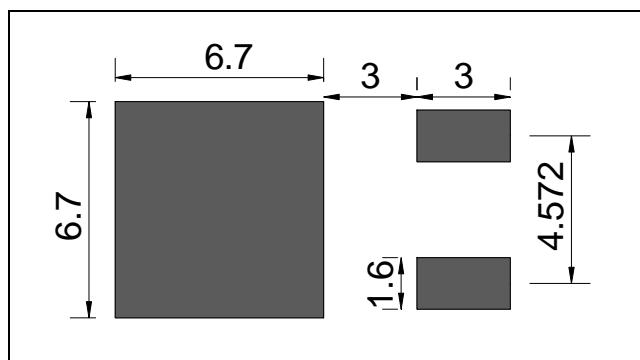
Date	Revision	Changes
Mar 1, 2019	14	Last update
Sep 8, 2021	15	Add V_{PP} Value
Apr 22, 2022	16	Add V_{TO} & R_d

PACKAGE MECHANICAL DATA

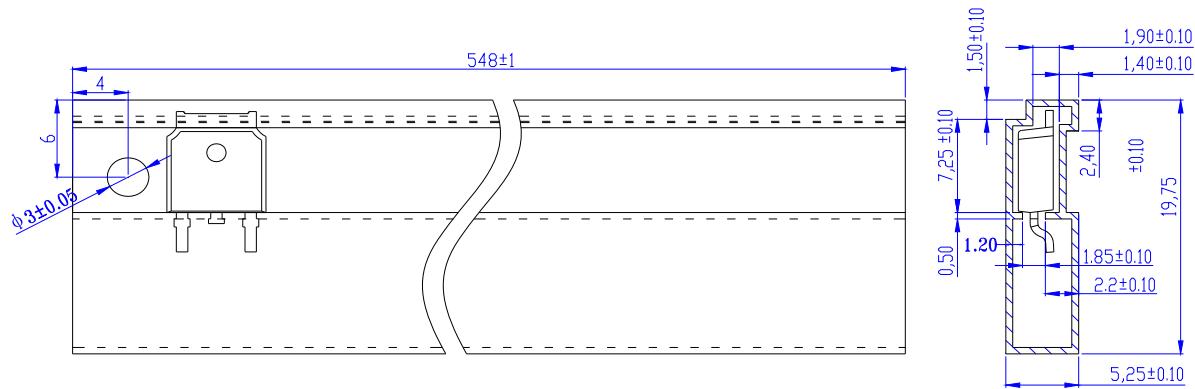


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

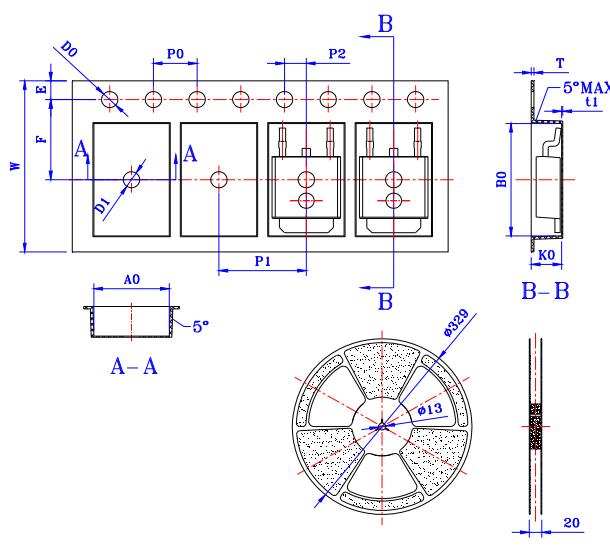
FOOTPRINT-TO-252-4R (dimensions in mm)



DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-252-4R	TUBE	80	4,000	20,000



Ref.	Dimensions					
	Millimeters			Inches		
Min.	Typ.	Max.	Min.	Typ.	Max.	
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
10P0	39.80	40.00	40.20	1.567	1.575	1.583
A0	6.85	6.90	7.00	0.270	0.272	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.106	0.109	0.113
T	0.24	—	0.27	0.009	—	0.011
t1	0.10	—	—	0.004	—	—

PACKAGE	OUTLINE	REEL (PCS)	PER CARTON (PCS)	TAPE & REEL
TO-252-4R	TAPING	2,500	25,000	13 inch



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